IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applications of: MACRONIX INTERNATIONAL CO., LTD.						
U.S. S	erial No: Listed on attached	1				
Filed:	Listed on attached	1				
Re:	e: Revocation of Power of Attorney with / New Power of Attorney and Change of /					
	Correspondence Address and Statement Under 37 C.F.R. 3.73(b)	1				

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage as first class mail in an envelope addressed to Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, or facsimile transmitted to: Commissioner for Patents at fax number (571) 273-8300 on January 7, 2008.

January 7, 2000.

Kenton R. Mullins, Reg. No. 36,331

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

TRANSMITTAL

Sir:

Submitted herewith are:

- (1) Revocation of Power of Attorney with New Power of Attorney and Change of Correspondence Address and Statement Under 37 C.F.R. 3.73(b); and
- (2) Deposit Account Authorization: The Commissioner is hereby authorized to charge any needed fees to deposit account 50-1600.

Respectfully submitted,

Kenton R. Mullins

Registration No. 36,331

January 7, 2008

STOUT, UXA, BUYAN & MULLINS, LLP 4 Venture, Suite 300 Irvine, CA 92618 Tel: 949-450-1750

Fax: 949-450-1764

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

REVOCATION OF POWER OF ATTORNEY WITH NEW POWER OF ATTORNEY AND CHANGE OF CORRESPONDENCE ADDRESS AND STATEMENT UNDER 37 C.F.R. 3.73(b)

Sir:

MACRONIX INTERNATIONAL CO., LTD., a corporation, states that it is the assignee of record of the entire right, title and interest of the below-identified patent applications by virtue of assignment from inventor(s) to assignee. I hereby revoke all previous powers of attorney given in the applications identified below and hereby appoint the practitioners associated with:

Customer No.: 33197.

A chain of title from the inventor(s) to the current assignee is shown below: <u>Patent Applications</u>

U.S. Patent	Filing Date	Title	Inventor(s)	Assignment Recorded from
Appln. No.				Inventor(s) to Assignee
				MACRONIX
				INTERNATIONAL CO.,
				LTD. At Reel/ Frame
3			LI, MINFU et al.	P900509USA.pdf
		Security Memory Device		
		and Method for Making		for which a copy thereof is
10/189,084	2002/7/3	Same		attached
		Method of improving	SU, CHIN-TA	014742/0715
		thermal stability for		
10/719,759	2003/11/20	cobalt salicide		
		Methods for sidewall	LIU, YUH-TURNG	015501/0414
		etching and etching		
10/872,086	2004/6/17	during filling of a trench		
10/948,891	2004/9/24	Chalcogenide memory	CHEN, YI CHOU	015831/0867
		Structure for phase	LEE, MING HSIU et	CA of US 10/966,335 (015905/0300)
		change memory and the	al.	
11/881,077	2007/7/24	method of forming same		
		Buried Bit Line Anti-Fuse	LUNG,	016863/0976
		One-Time-Programmable	HSIANG-LAN	
11/123,589	2005/5/6	Nonvolatile Memory		
11/134,155	2005/5/20	Air tunnel floating gate	LUE, HANG-TING et	016589/0306

		memory cell and method	al	
		for making the same	ш,	
			TSENG,	017040 /0100
		Self-adjusting clock		017268/0198
11 /010 006	2005 (0 /2	generator with stable	CHIEN-CHUNG	
11/218,806	2005/9/2	frequency output		
		Nitride read only	LIU, CHIEN HUNG	017102/0270
	:	memory device with		
		buried diffusion spacers		
		and method for making		
11/250,959	2005/10/14	the same		
		Method to prevent	YANG, CHIN	017123/0737
		anti-assist feature and	CHENG	
		side lobe from printing		
11/255,761	2005/10/21	out		
		Method to form photo	YANG, CHIN	017138/0981
11/255,791	2005/10/21	patterns	CHENG	
		NAND Type Multi-Bit	CHEN, YIN JEN et al.	017276/0621
		Charge Storage Memory		
		Array and Methods for		
		Operating and		
11/285,919	2005/11/23	Fabricating the Same		
		Method for forming	LUOH, TUUNG et al.	017771/0484
		self-aligned contacts and		
		local interconnects		
11/399,770	2006/4/7	simultaneously		
11/0/0///	2000/ 1/ /	High Aspect-Ratio	WU, CHAO-I et al.	016157/0573
		PN-Junction and Method	,,	,
		for Manufacturing the		
11/027,807	 2004/12/30			
11/ 027,807	2004/12/30	METHOD FOR NROM	HUNG,	
		ARRAY WORD LINE		
		RETRY ERASING AND	chon-historia et	Di470090101152 5.PDF
			al.	
		THRESHOLD		for which a copy thereof is
44 (==0.004	000818148	VOLTAGE		attached
11/750,296	2007/5/17	RECOVERING	HO CHILLIAN A	
		Magnetic Random	HO, CHIAHUA et al.	U16364/ U634
		Access Memory Using		
		Single Crystal		
11/420,930	2006/5/30	Self-aligned Diode		

I am empowered to act on behalf of the assignee.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon .

Respectfully submitted,

MACRONIX INTERNATIONAL CO., LTD.

Date: JAN - 3 2008

by: Billie Chen, Director of IP & Legal Office MACRONIX INTERNATIONAL CO., LTD.